



# CPH3123 / CPH3223 — PNP / NPN Epitaxial Planar Silicon Transistors

## High-Current Switching Applications

### Applications

- DC-DC converter, relay drivers, lamp drivers, motor drivers, flash.

### Features

- Adoption of MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm).
- High allowable power dissipation.

### Specifications ( ) : CPH3123

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CB0</sub>		(-50)100	V
Collector-to-Emitter Voltage	V <sub>CES</sub>		(-50)100	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(-)50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)6	V
Collector Current	I <sub>C</sub>		(-)3	A
Collector Current (Pulse)	I <sub>CP</sub>		(-)6	A
Base Current	I <sub>B</sub>		(-)600	mA
Collector Dissipation	P <sub>C</sub>	Mounted on a ceramic board (600mm <sup>2</sup> X0.8mm)	0.9	W
Junction Temperature	T <sub>J</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(-)1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(-)1	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)100mA	200		560	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)500mA		(390)380		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		(24)13		pF

Marking : CPH3123 : AU, CPH3223 : CU

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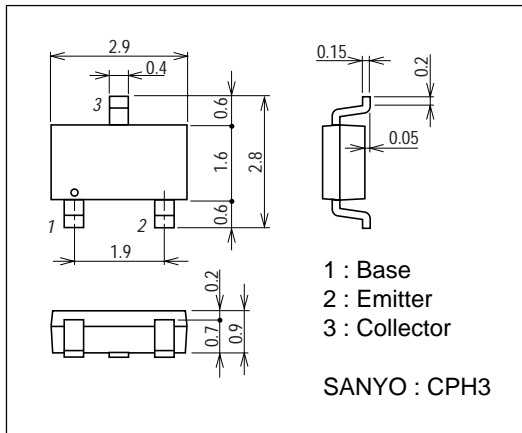
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)1A, I_B = (-)50mA$		(-115)90	(-230)130	mV
		$I_C = (-)2A, I_B = (-)100mA$		(-240)160	(-650)240	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)2A, I_B = (-)100mA$		(-0.88)	(-1.2)	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0$	(-50)100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C = (-)100\mu A, R_{BE} = 0$	(-50)100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0$	(-6)			V
Turn-ON Time	$t_{on}$	See specified Test Circuit.		(30)35		ns
Storage Time	$t_{stg}$	See specified Test Circuit.		(230)300		ns
Fall Time	$t_f$	See specified Test Circuit.		(18)25		ns

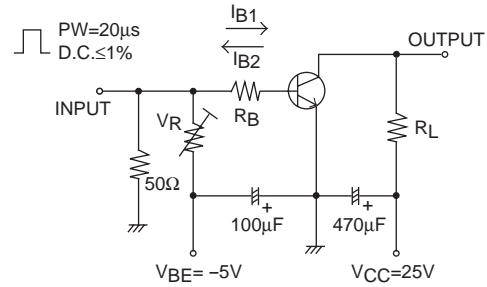
## Package Dimensions

unit : mm

2150A

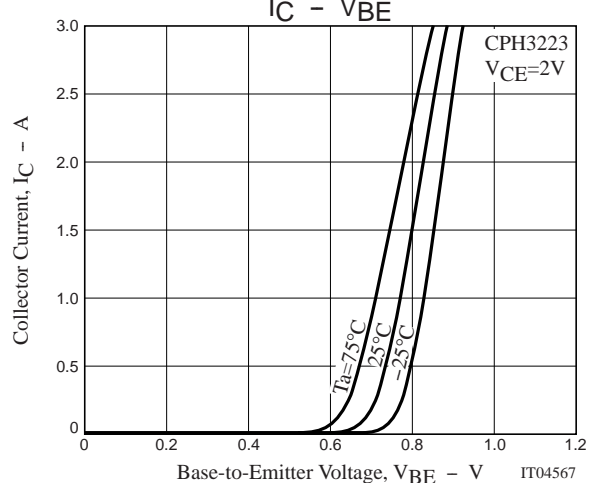
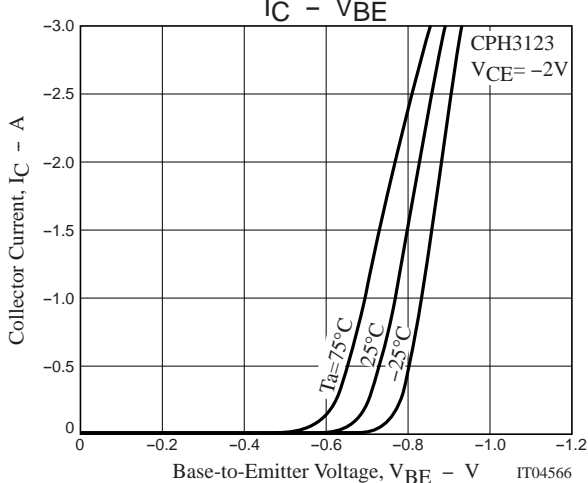
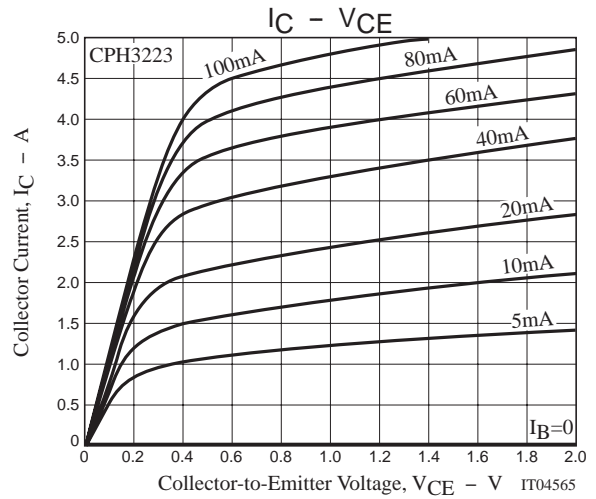
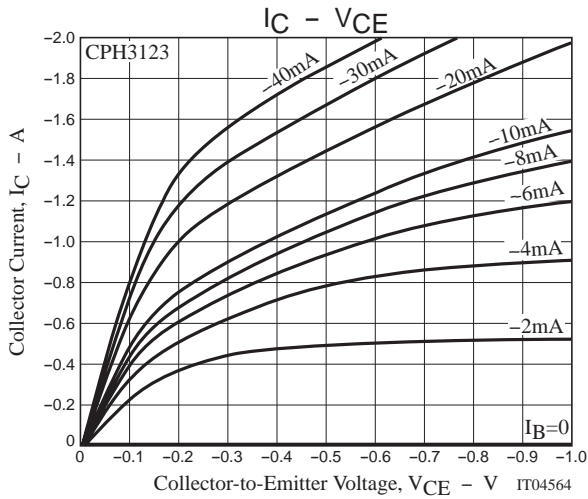


## Switching Time Test Circuit

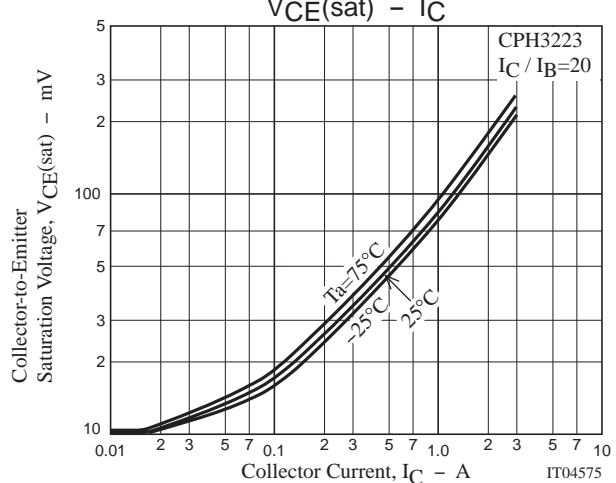
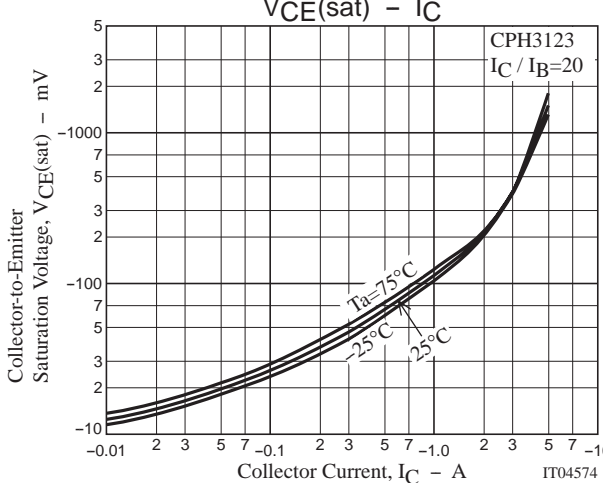
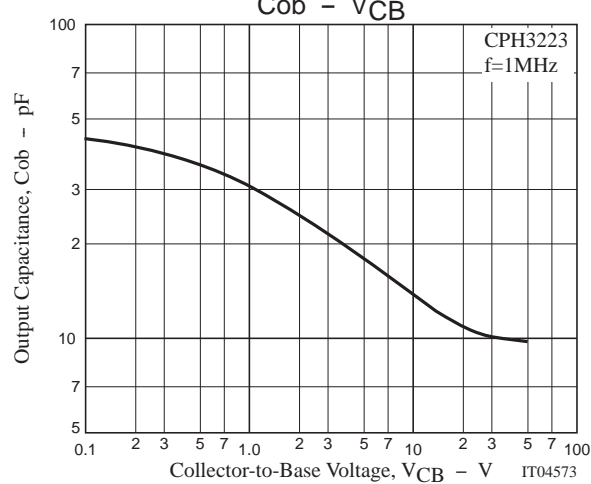
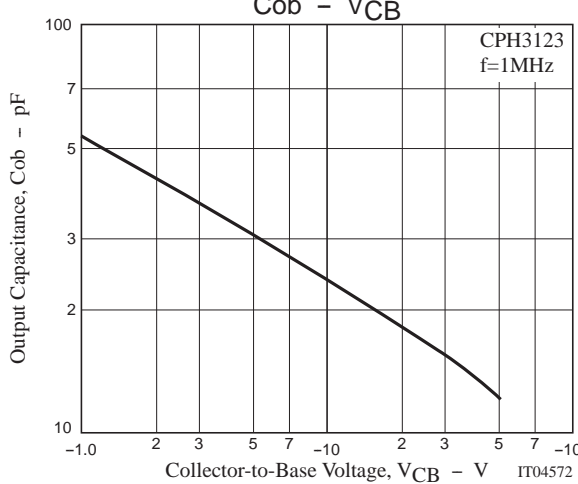
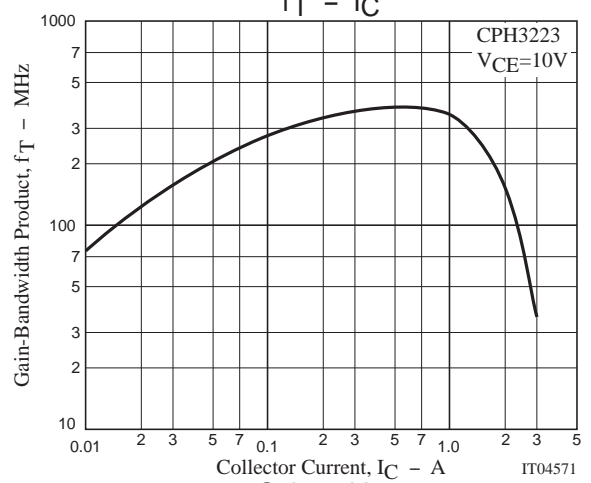
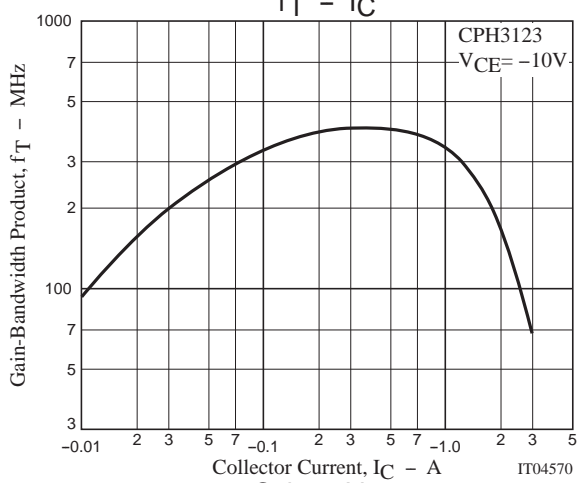
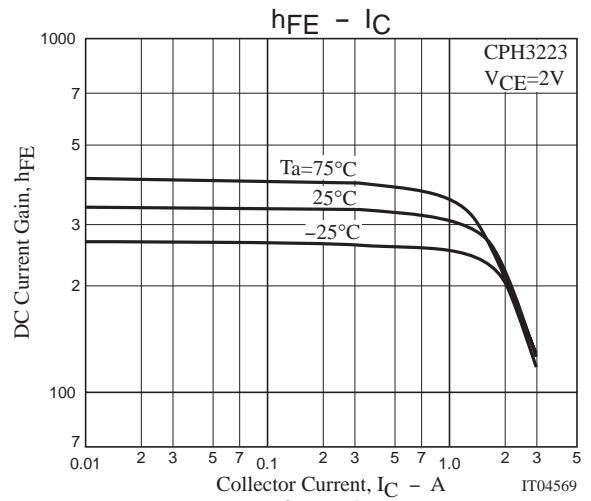
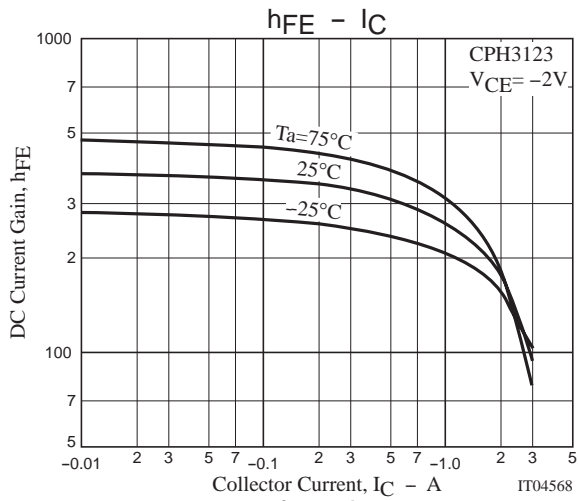


$$I_C = 10I_{B1} = -10I_{B2} = 1A$$

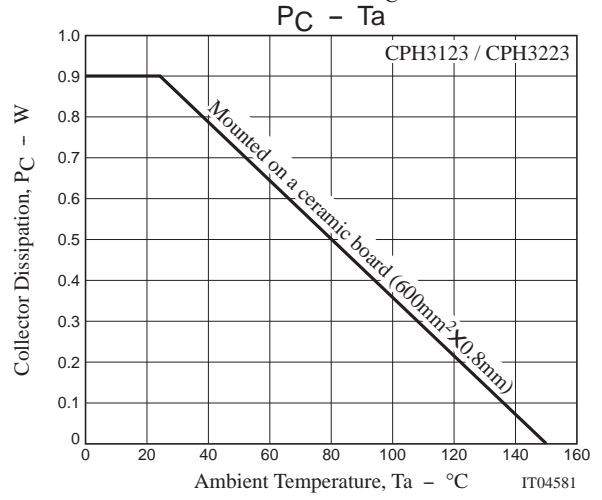
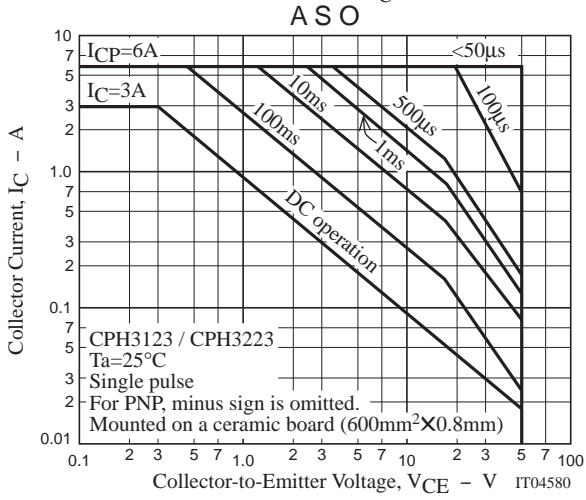
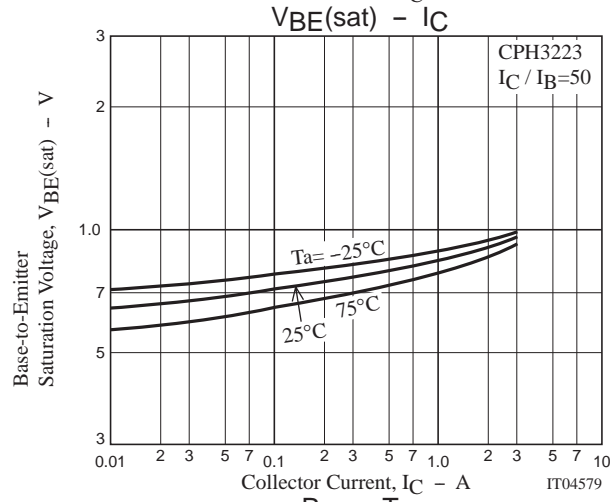
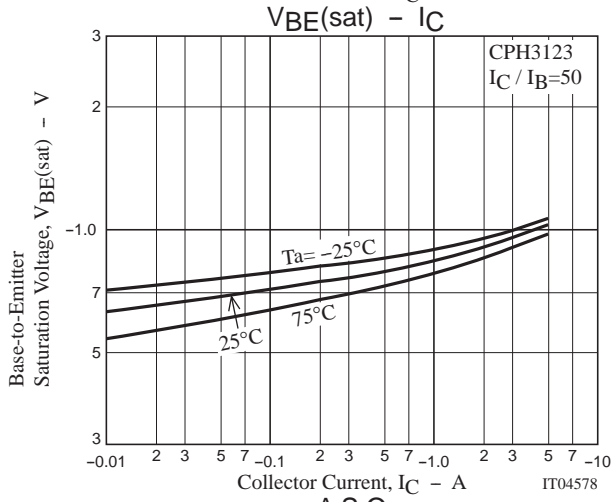
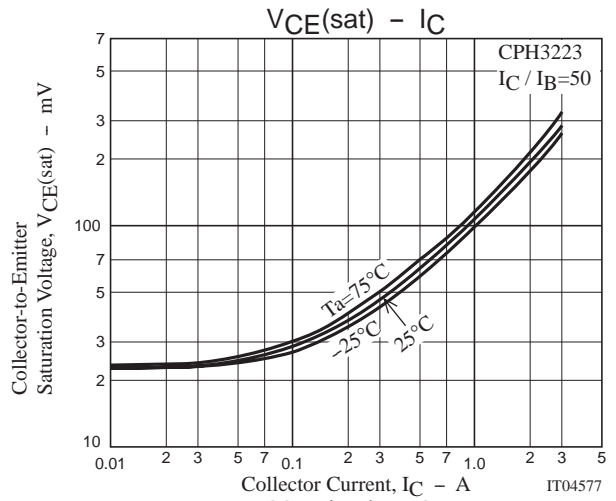
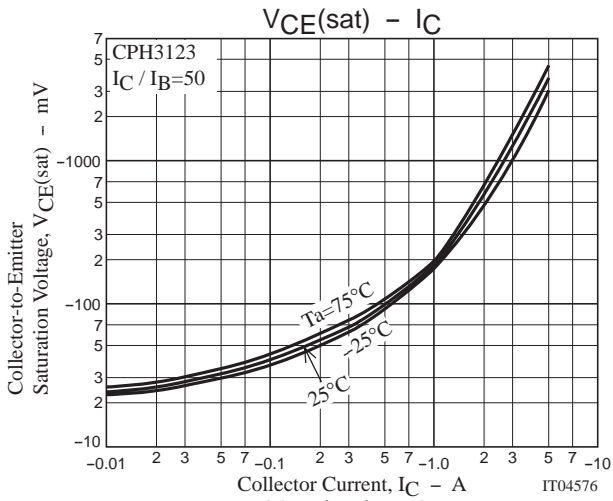
For PNP, the polarity is reversed.



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